



Schottky Diode Gen²

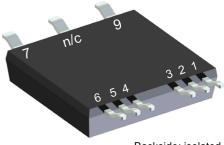
 $V_{RRM} = 150 V$ $I_{FAV} = 2x 75 A$ $V_{F} = 0.74 V$

High Performance Schottky Diode Low Loss and Soft Recovery Parallel legs

Part number

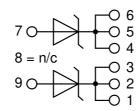
DSA120X150LB

Marking on Product: DSA120X150LB



Backside: isolated





Features / Advantages:

- Very low Vf
- Extremely low switching losses
- Low Irm values
- Improved thermal behaviour
- High reliability circuit operation
- Low voltage peaks for reduced protection circuits
- Low noise switching

Applications:

- Rectifiers in switch mode power supplies (SMPS)
- Free wheeling diode in low voltage converters

Package: SMPD

- Isolation Voltage: 3000 V~
- Industry convenient outline
- RoHS compliant
- Epoxy meets UL 94V-0
- Soldering pins for PCB mounting
- Backside: DCB ceramic
- Reduced weight
- Advanced power cycling

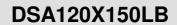
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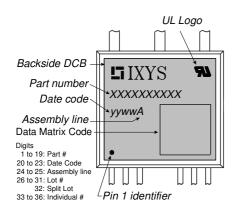


Schottky				Ratings			
Symbol	Definition	Conditions		min.	typ.	max.	Unit
V _{RSM}	max. non-repetitive reverse block	ing voltage	$T_{VJ} = 25^{\circ}C$			150	V
V_{RRM}	max. repetitive reverse blocking v	oltage	$T_{VJ} = 25^{\circ}C$			150	V
IR	reverse current, drain current	$V_R = 150 \text{ V}$	$T_{VJ} = 25^{\circ}C$			1	mA
		$V_R = 150 \text{ V}$	$T_{VJ} = 125^{\circ}C$			5	mΑ
V _F	forward voltage drop	I _F = 60 A	$T_{VJ} = 25^{\circ}C$			0.93	٧
		$I_{F} = 120 \text{ A}$				1.13	V
		$I_F = 60 \text{ A}$	T _{vJ} = 125°C			0.74	V
		$I_F = 120 A$				0.95	٧
I _{FAV}	average forward current	T _c = 135°C	T _{vJ} = 175°C			75	Α
		rectangular $d = 0.5$					
V _{F0}	threshold voltage slope resistance $T_{VJ} = 175$ °C for power loss calculation only					0.51	٧
r _F						1.3	mΩ
R _{thJC}	thermal resistance junction to cas	e				0.8	K/W
R _{thCH}	thermal resistance case to heatsing	nk			0.40		K/W
P _{tot}	total power dissipation		$T_C = 25^{\circ}C$			185	W
I _{FSM}	max. forward surge current	$t = 10 \text{ ms}$; (50 Hz), sine; $V_R = 0 \text{ V}$	$T_{VJ} = 45^{\circ}C$			700	Α
C	junction capacitance	$V_{R} = 24 V f = 1 MHz$	$T_{VJ} = 25^{\circ}C$		481		pF





Package SMPD				ı	Ratings			
Symbol	Definition	Conditions		min.	typ.	max.	Unit	
I _{RMS}	RMS current	per terminal				100	Α	
T _{VJ}	virtual junction temperature			-55		175	°C	
T _{op}	operation temperature			-55		150	°C	
T _{stg}	storage temperature			-55		150	°C	
Weight					8.5		g	
F _c	mounting force with clip			40		130	N	
$d_{\text{Spp/App}}$	creepage distance on surface striking distance through air		terminal to terminal	1.6			mm	
$d_{\text{Spb/Apb}}$			terminal to backside	4.0			mm	
V _{ISOL}	isolation voltage $t = 1 \ \text{second}$ $t = 1 \ \text{minute}$	t = 1 second	50/60 Hz, RMS; IsoL ≤ 1 mA	3000			V	
		t = 1 minute		2500			٧	



Part description

D = Diode

S = Schottky Diode

A = low VF

120 = Current Rating [A]

X = Parallel legs

150 = Reverse Voltage [V]

LB = SMPD-B

Ordering	Ordering Number	Marking on Product	Delivery Mode	Quantity	Code No.
Standard	DSA120X150LB-TUB	DSA120X150LB	Tube	20	524766
Alternative	DSA120X150LB-TRR	DSA120X150LB	Tape & Reel	200	517173

Equivalent Circuits for Simulation			* on die level	$T_{VJ} = 175 ^{\circ}C$
$I \rightarrow V_0$	-R _o -	Schottky		
V _{0 max}	threshold voltage	0.51		V
$R_{0 max}$	slope resistance *	1.3		$m\Omega$



Outlines SMPD

